

MJE3439

**0.3 AMPERE
POWER TRANSISTOR
NPN SILICON
350 VOLTS
15 WATTS**

NPN Silicon High-Voltage Power Transistors

... designed for use in line-operated equipment requiring high f_T .

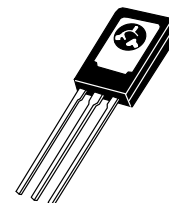
- High DC Current Gain
 $h_{FE} = 40-160 @ I_C = 20 \text{ mAdc}$
- Current Gain Bandwidth Product —
 $f_T = 15 \text{ MHz (Min) @ } I_C = 10 \text{ mAdc}$
- Low Output Capacitance
 $C_{ob} = 10 \text{ pF (Max) @ } f = 1.0 \text{ MHz}$

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	350	Vdc
Collector-Base Voltage	V_{CB}	450	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current — Continuous	I_C	0.3	Adc
Base Current	I_B	150	mAdc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	15 0.12	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	8.33	$^\circ\text{C/W}$



**CASE 77-08
TO-225AA TYPE**

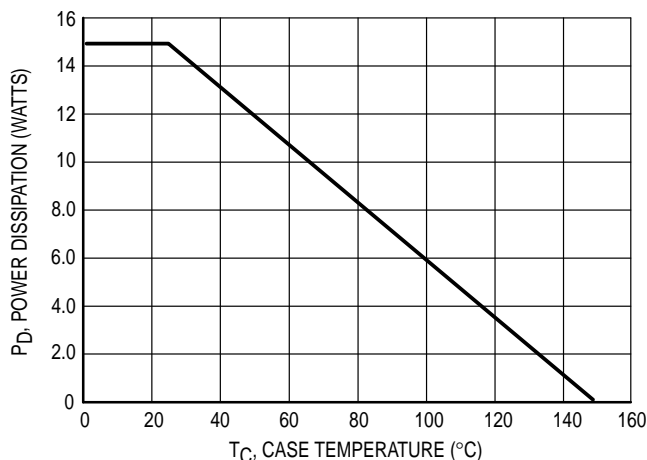


Figure 1. Power-Temperature Derating Curve

MJE3439

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (I _C = 5.0 mA _{dc} , I _B = 0)	V _{CEO(sus)}	350	—	V _{dc}
Collector Cutoff Current (V _{CE} = 300 V _{dc} , I _B = 0)	I _{CEO}	—	20	μA _{dc}
Collector Cutoff Current (V _{CE} = 450 V _{dc} , V _{EB(off)} = 1.5 V _{dc})	I _{CEX}	—	500	μA _{dc}
Collector Cutoff Current (V _{CB} = 350 V _{dc} , I _E = 0)	I _{CBO}	—	20	μA _{dc}
Emitter Cutoff Current (V _{BE} = 5.0 V _{dc} , I _C = 0)	I _{EBO}	—	20	μA _{dc}

ON CHARACTERISTICS

DC Current Gain (I _C = 2.0 mA _{dc} , V _{CE} = 10 V _{dc}) (I _C = 20 mA _{dc} , V _{CE} = 10 V _{dc})	h _{FE}	30 15	— 200	—
Collector–Emitter Saturation Voltage (I _C = 50 mA _{dc} , I _B = 4.0 mA _{dc})	V _{CE(sat)}	—	0.5	V _{dc}
Base–Emitter Saturation Voltage (I _C = 50 mA _{dc} , I _B = 4.0 mA _{dc})	V _{BE(sat)}	—	1.3	V _{dc}
Base–Emitter On Voltage (I _C = 50 mA _{dc} , V _{CE} = 10 V _{dc})	V _{BE(on)}	—	0.8	V _{dc}

DYNAMIC CHARACTERISTICS

Current–Gain — Bandwidth Product (I _C = 10 mA _{dc} , V _{CE} = 10 V _{dc} , f = 5.0 MHz)	f _T	15	—	MHz
Output Capacitance (V _{CB} = 10 V _{dc} , I _E = 0, f = 1.0 MHz)	C _{ob}	—	10	pF
Small–Signal Current Gain (I _C = 5.0 mA _{dc} , V _{CE} = 10 V _{dc} , f = 1.0 kHz)	h _{fe}	25	—	—

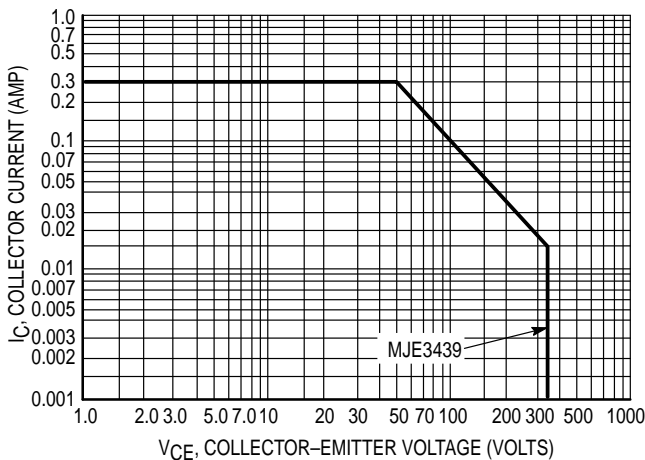
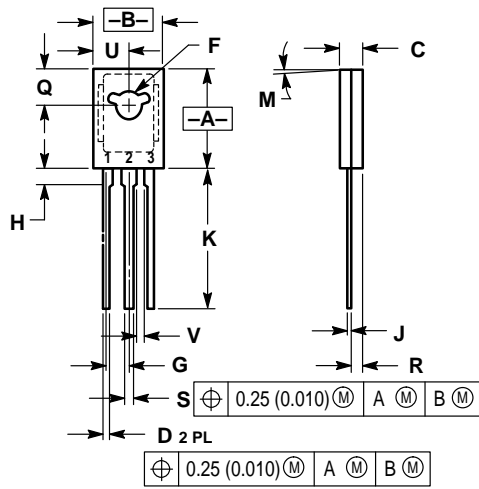


Figure 2. Active–Region Safe Operating Area

The Safe Operating Area Curves indicate I_C – V_{CE} limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum T_J, power–temperature derating must be observed for both steady state and pulse power conditions.

PACKAGE DIMENSIONS




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.425	0.435	10.80	11.04
B	0.295	0.305	7.50	7.74
C	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
H	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.055	1.15	1.39
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
V	0.040	—	1.02	—

- STYLE 1:
 PIN 1. EMITTER
 2. COLLECTOR
 3. BASE

CASE 77-08
 TO-225AA TYPE
 ISSUE V

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